

ZVN4310G

#### 100V N-CHANNEL ENHANCEMENT MODE VERTICAL MOSFET IN SOT223

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> T <sub>A</sub> = +25°C
100V	0.54Ω @ V <sub>GS</sub> = 10V	1.67A
	0.75Ω @ V <sub>GS</sub> = 5V	1.42A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for highefficiency power-management applications.

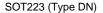
- DC-DC converters
- Solenoids/relay driver for automotive applications

### **Features and Benefits**

- BV<sub>DSS</sub> > 100V
- R<sub>DS(ON)</sub> ≤ 0.54Ω @ V<sub>GS</sub> = 10V
- Maximum Continuous Drain Current I<sub>D</sub> = 1.67A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

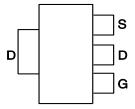
#### **Mechanical Data**

- Package: SOT223
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

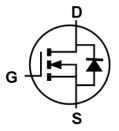




Top View



Pin Out - Top View



**Equivalent Circuit** 

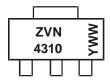
#### **Ordering Information** (Note 4)

Orderable Part Number	Daakaga	Packing		
	Package	Qty.	Carrier	
ZVN4310GTA	SOT223 (Type DN)	1,000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



ZVN4310 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 4 = 2024) WW or  $\overline{WW}$  = Week Code (01 to 53)



### **Maximum Ratings** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	VDSS	100	V
Gate-Source Voltage	Vgss	±20	V
Continuous Drain Current	I <sub>D</sub>	1.67	Α
Pulsed Drain Current (Note 6)	IDM	12	А

### Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	PD	3	W
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{ heta JA}$	41.7	°C/W
Thermal Resistance, Junction to Leads	(Note 7)	Rejl	8.84	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

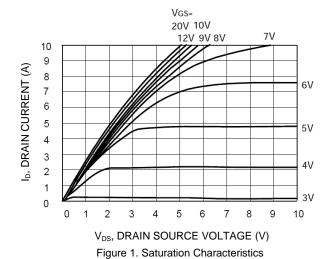
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_		V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current, T <sub>J</sub> = +25°C	IDSS			10 100	μA μA	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V V <sub>DS</sub> = 80V, V <sub>GS</sub> = 0V, T <sub>A</sub> = +125°C	
Gate-Source Leakage	Igss		_	±20	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
On-State Drain Current	I <sub>D(ON)</sub>	9	_		Α	V <sub>G</sub> S = 10V, V <sub>D</sub> S = 10V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(TH)	1	_	3	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$	
Static Drain-Source On-Resistance	RDS(ON)	_	0.4 0.5	0.54 0.75	Ω	$V_{GS} = 10V, I_D = 3.3A$ $V_{GS} = 5V, I_D = 1.5A$	
Forward Transconductance	<b>g</b> fs	0.6	_	_	S	$V_{DS} = 10V, I_D = 3.3A$	
DYNAMIC CHARACTERISTICS (Note 8)					•		
Input Capacitance	Ciss		_	350	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	_	140	pF		
Reverse Transfer Capacitance	Crss	_	_	20	pF		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	_	8	ns	$V_{DD}=25V,\ I_{D}=3A,\ V_{GEN}=10V,$ $R_{GS}=50\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	_	25	ns		
Turn-Off Delay Time	tD(OFF)	_	_	30	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	_	16	ns		

- 5. For a device mounted on 50mm X 50mm X 1.6mm FR-4 PCB with high coverage of single sided 2oz copper, in still air condition.
- 6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
- 7. Thermal resistance from junction to solder-point (at the end of the drain lead).
  8. Short duration pulse test used to minimize self-heating effect.



### **Electrical Characteristics**



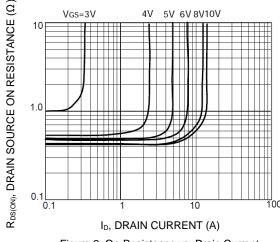
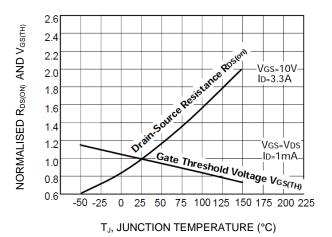


Figure 2. On-Resistance vs. Drain Current



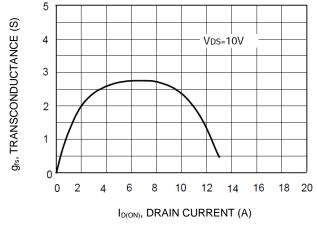
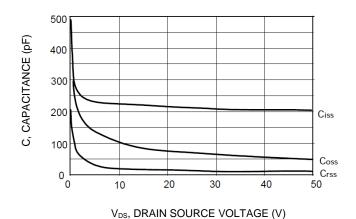


Figure 3. Normalised  $R_{\text{DS(ON)}}$  and  $V_{\text{GS(TH)}}$  vs. Temperature

Figure 4. Transconductance vs. Drain Current



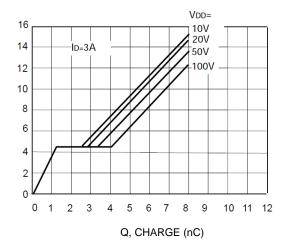


Figure 5. Capacitance vs. Drain-Source Voltage

Figure 6. Gate Charge vs. Gate-Source Voltage

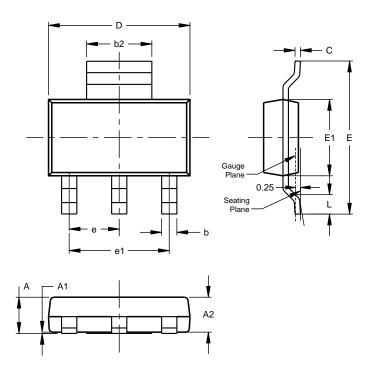
V<sub>GS</sub>, GATE SOURCE VOLTAGE (V)



# **Package Outline Dimensions**

 $\label{lem:please} Please see \ http://www.diodes.com/package-outlines.html for the latest version.$ 

#### SOT223 (Type DN)

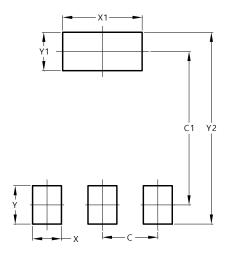


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α		1.70	-	
A1	0.01	0.15	-	
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
С	0.20	0.32		
D	6.30	6.70	-	
Е	6.70	7.30	-	
E1	3.30	3.70	-	
е			2.30	
e1			4.60	
L	0.85			
All Dimensions in mm				

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8 00



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ZVN4310G 5 of 5 August 2024

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